

WEST Search History

DATE: Monday, September 27, 2004

Hide?	Set Name	Query	Hit Count
		<i>DB=TDBD,DWPI,JPAB,EPAB,USPT; PLUR=YES; OP=OR</i>	
<input type="checkbox"/>	L1	(VERHAVERBEKE-STEVEN)!	22
<input type="checkbox"/>	L2	TRUMAN-J-KELLY!	3

END OF SEARCH HISTORY

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	IS&R	L1	41	((("3,045,702") or ("3,291,347") or ("4,243,071") or ("4,554,050") or ("4,671,852") or ("4,899,767") or ("5,071,547") or ("5,134,445") or ("5,302,311") or ("5,346,302") or ("5,466,389") or ("5,490,611") or ("5,678,116") or ("5,853,491") or ("5,885,362") or ("5,908,509") or ("5,938,847") or ("5,962,384") or ("5,972,123") or ("6,132,522"))).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 17:06			0
2	IS&R	L2	2	("5071547").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 17:22			0
3	IS&R	L3	2	("20020102852").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 17:31			0
4	BRS	L4	1	"acoustic waves" and 3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 18:54			0
5	BRS	L5	736	((spin\$4 or rotat\$5) with (wafer or substrate or semiconductor)) same (acoustic or sonic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 18:09			0
6	BRS	L6	360	((spin\$4 or rotat\$5) with (wafer or substrate or semiconductor)) with(acoustic or sonic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 17:39			0
7	BRS	L7	217	6 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 19:08			0
8	BRS	L8	103	5 and 134/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 18:10			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
9	BRS	L9	91	8 not 7	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 18:10			0
10	BRS	L10	1	"hydrophilic surface" and 3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 19:05			0
11	BRS	L11	282	(degas\$4 with ("H.sub.2O" or water or "DI")) same (dissolv\$3 with ("O.sub.2" or "O.sub.3" or oxygen or ozone))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 19:08			0
12	BRS	L12	22	11 same (wafer or substrate or semiconductor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 19:08			0
13	BRS	L13	1601417	"52" and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 19:09			0
14	BRS	L14	11	12 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 19:48			0
15	BRS	L15	5	((clean\$3 or etch\$3) with (wafer or substrate or semiconductor) with (chelate\$3 with surfactant)) and ((wash\$3 or rins\$3) with (wafer or substrate or semiconductor) with ((water or "H.sub.2O" or DI) and (oxid\$5 or oxygen or ozone or "O.sub.3" or peroxide or "H.sub.2O.sub.2" or "O.sub.3"))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 19:47			0
16	BRS	L16	209	remov\$3 with (HF or hydrofluoric) with (spin\$4 or rotat\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 19:48			0
17	BRS	L17	124	16 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 19:49			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L1	87	("NH.sub.OH" or "ammonium hydroxide") same molybdc	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 12:42			0
2	BRS	L2	65	("NH.sub.OH" or "ammonium hydroxide") with molybdc	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 12:43			0
3	BRS	L3	0	2 not 1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 12:42			0
4	BRS	L4	56	2 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 12:44			0
5	BRS	L5	0	((("NH.sub.OH" or "ammonium hydroxide") with molybdc) same (clean\$3 or etch\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 12:44			0
6	BRS	L7	7	6 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 12:44			0
7	BRS	L6	10	((("NH.sub.OH" or "ammonium hydroxide") with molybdc) and (clean\$3 or etch\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 13:38			0
8	IS&R	L8	2	("4051057").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 14:56			0
9	BRS	L9	0	rins\$3 same ("POU" or "point of use") same (oxygen or ozone or oxygen or ozone or "O.sub.2" or "O.sub.3").	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 14:59			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
10	BRS	L1 0	0	rins\$3 same ("POU" or "point of use") same (oxygen or ozone or oxygen or ozone or "O.sub.2" or "O.sub.3")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 14:59			0
11	BRS	L1 1	6	rins\$3 same ("POU" or "point of use")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 15:01			0
12	BRS	L1 2	0	rins\$3 same ("POU" or "point of use") same (oxygen or ozone or oxygen or ozone or "O.sub.2" or "O.sub.3")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 15:02			0
13	BRS	L1 3	3	rins\$3 and (("POU" or "point of use") same (oxygen or ozone or oxygen or ozone or "O.sub.2" or "O.sub.3"))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 15:05			0
14	BRS	L1 4	208	etch\$3 with HF with angstrom	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 15:35			0
15	BRS	L1 5	1	14 same (remov\$3 with HF with spin\$4 or rotat\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 15:30			0
16	BRS	L1 6	137	14 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 15:37			0
17	BRS	L1 7	193	(etch\$3 with HF) same ("SiO.sub.2" or "silicon oxide") same angstrom	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 15:54			0
18	BRS	L1 8	140	17 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 15:55			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
19	BRS	L1 9	25	(etch\$3 with HF) same (remov\$3 with ("SiO.sub.2" or "silicon oxide") with angstrom)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 15:59			0
20	BRS	L2 0	19	19 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 16:00			0
21	BRS	L2 1	676	(etch\$3 with ("SiO.sub.2" or "silicon oxide") with angstrom)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 16:14			0
22	BRS	L2 2	442	21 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 16:09			0
23	BRS	L2 4	4	22 and 438/745	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 16:01			0
24	BRS	L2 5	13	22 and 134/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 16:04			0
25	BRS	L2 3	292	22 and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 16:06			0
26	BRS	L2 6	51	21 same (HF or hydrfluoric)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 16:08			0
27	BRS	L2 7	33	26 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 16:15			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
28	BRS	L2 9	18	(clean\$3 with ("SiO.sub.2" or "silicon oxide") with angstrom) same (HF or hydrofluoric)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 16:15			0
29	BRS	L3 0	15	29 and @pd<=20010625	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/27 16:57			0